

BTA204S series B and C

Three-quadrant triacs high commutation

Rev. 03 — 24 May 2005

Product data sheet

1. Product profile

1.1 General description

Passivated high commutation triac in a SOT428 (DPAK) plastic package. Intended for use in circuits where high static and dynamic dV/dt and high dI/dt can occur. These devices will commute the full rated RMS current at the maximum rated junction temperature, without the aid of a snubber.

1.2 Features

- High maximum junction temperature
- High commutation capability

1.3 Applications

- Motor control
- Industrial and domestic heating

1.4 Quick reference data

- $V_{DRM} \leq 600$ V (BTA204S-600B)
- $V_{DRM} \leq 800$ V (BTA204S-800B)
- $V_{DRM} \leq 600$ V (BTA204S-600C)
- $V_{DRM} \leq 800$ V (BTA204S-800C)
- $I_{TSM} \leq 25$ A
- $I_{T(RMS)} \leq 4$ A

2. Pinning information

Table 1: Pinning

Pin	Description	Simplified outline	Symbol
1	main terminal 1 (T1)	<p>SOT428 (DPAK)</p>	
2	main terminal 2 (T2)		
3	gate (G)		
mb	mounting base [1]		

[1] Connected to main terminal 2 (T2)

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3. Ordering information

Table 2: Ordering information

Type number	Package		Version
	Name	Description	
BTA204S-600B	DPAK	plastic single-ended surface mounted package; 3 leads (one lead cropped)	SOT428
BTA204S-600C			
BTA204S-800B			
BTA204S-800C			

4. Limiting values

Table 3: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DRM}	repetitive peak off-state voltage	BTA204S-600B; BTA204S-600C	[1] -	600	V
		BTA204S-800B; BTA204S-800C	-	800	V
$I_{T(RMS)}$	RMS on-state current	full sine wave; $T_{mb} \leq 107\text{ °C}$; see Figure 4 and 5	-	4	A
I_{TSM}	non-repetitive peak on-state current	full sine wave; $T_j = 25\text{ °C}$ prior to surge; see Figure 2 and 3			
		$t = 20\text{ ms}$	-	25	A
		$t = 16.7\text{ ms}$	-	27	A
I^2t	I^2t for fusing	$t = 10\text{ ms}$	-	3.1	A ² s
di_T/dt	repetitive rate of rise of on-state current after triggering	$I_{TM} = 6\text{ A}$; $I_G = 0.2\text{ A}$; $di_G/dt = 0.2\text{ A}/\mu\text{s}$	-	100	A/ μs
I_{GM}	peak gate current		-	2	A
V_{GM}	peak gate voltage		-	5	V
P_{GM}	peak gate power		-	5	W
$P_{G(AV)}$	average gate power	over any 20 ms period	-	0.5	W
T_{stg}	storage temperature		-40	+150	°C
T_j	junction temperature		-	125	°C

- [1] Although not recommended, off-state voltages up to 800 V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 6 A/ μs .

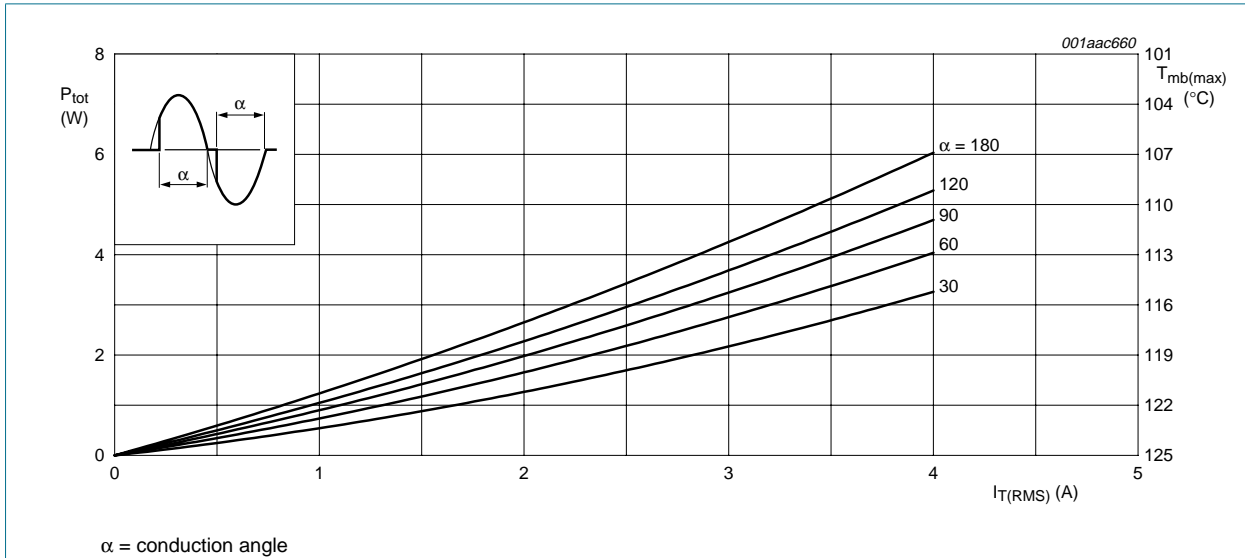


Fig 1. Total power dissipation as a function of RMS on-state current; maximum values

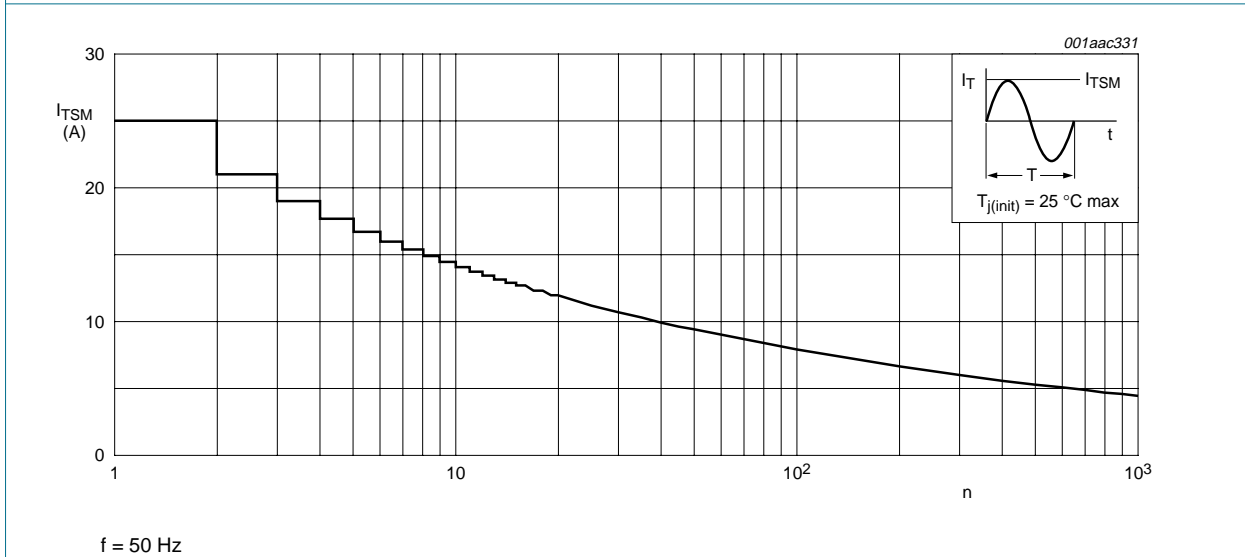
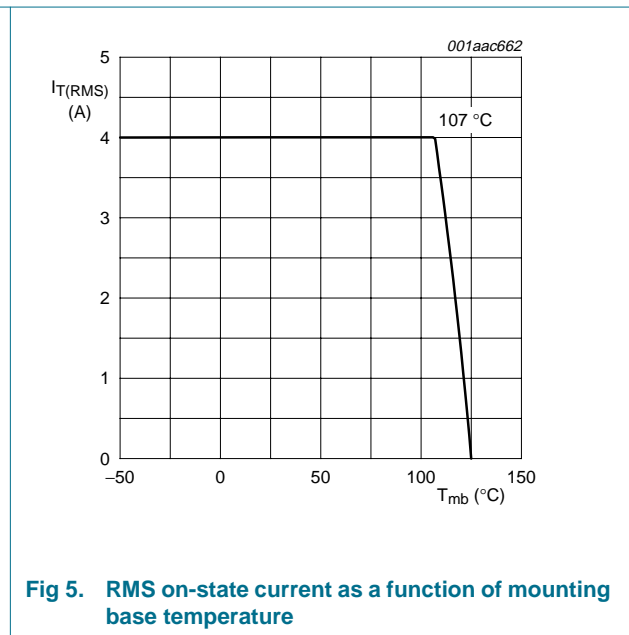
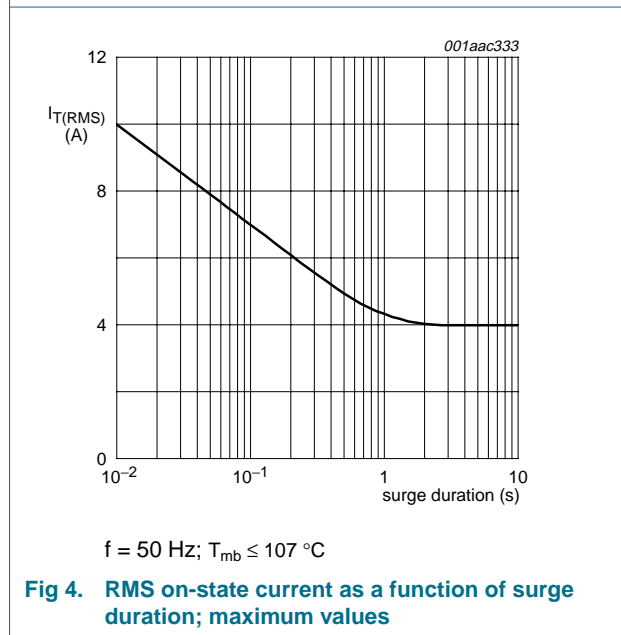
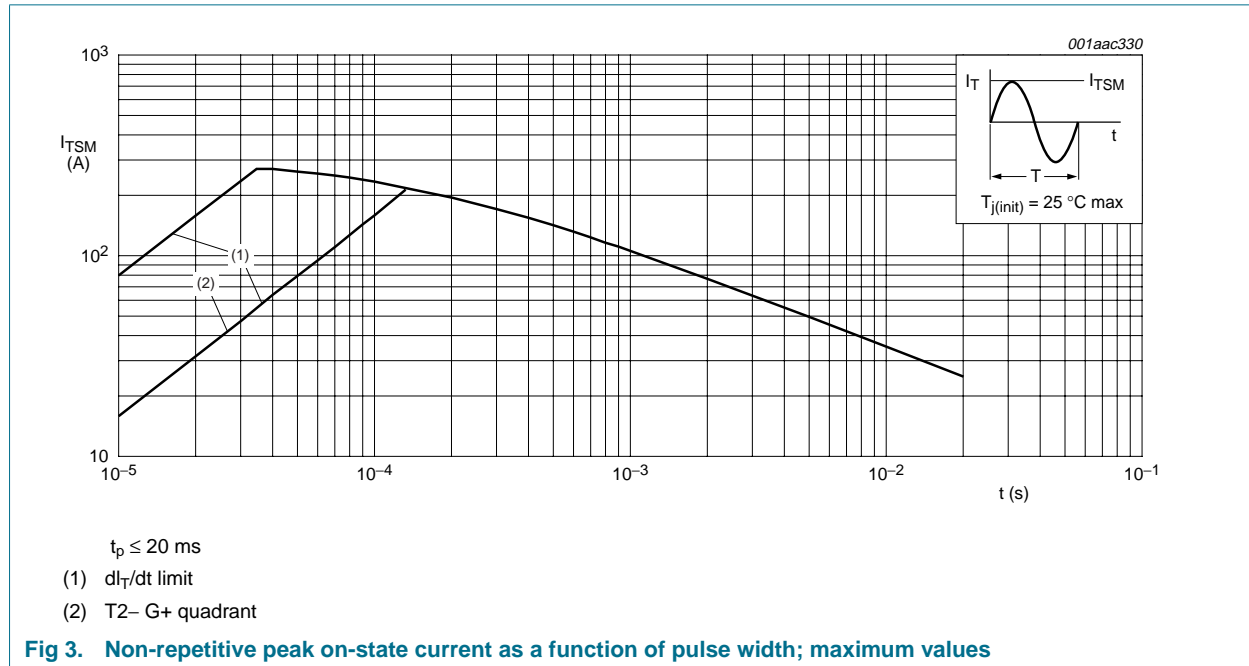


Fig 2. Non-repetitive peak on-state current as a function of the number of sinusoidal cycles; maximum values



5. Thermal characteristics

Table 4: Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	full cycle	-	-	3.0	K/W
		half cycle	-	-	3.7	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	printed-circuit board (FR4) mounted as in Figure 13	-	75	-	K/W

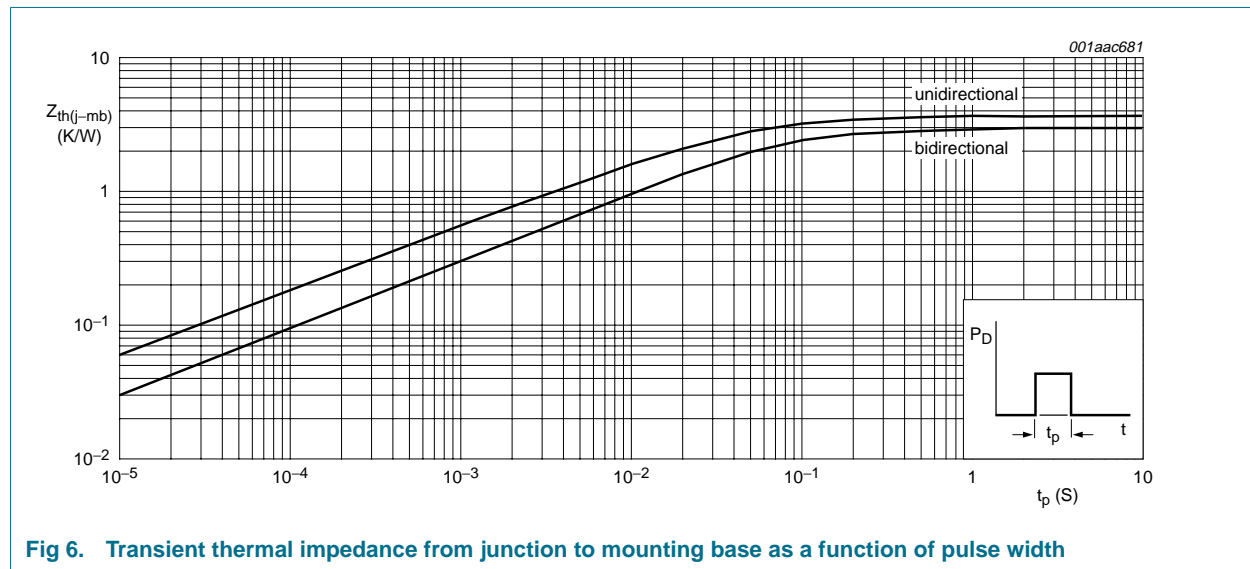


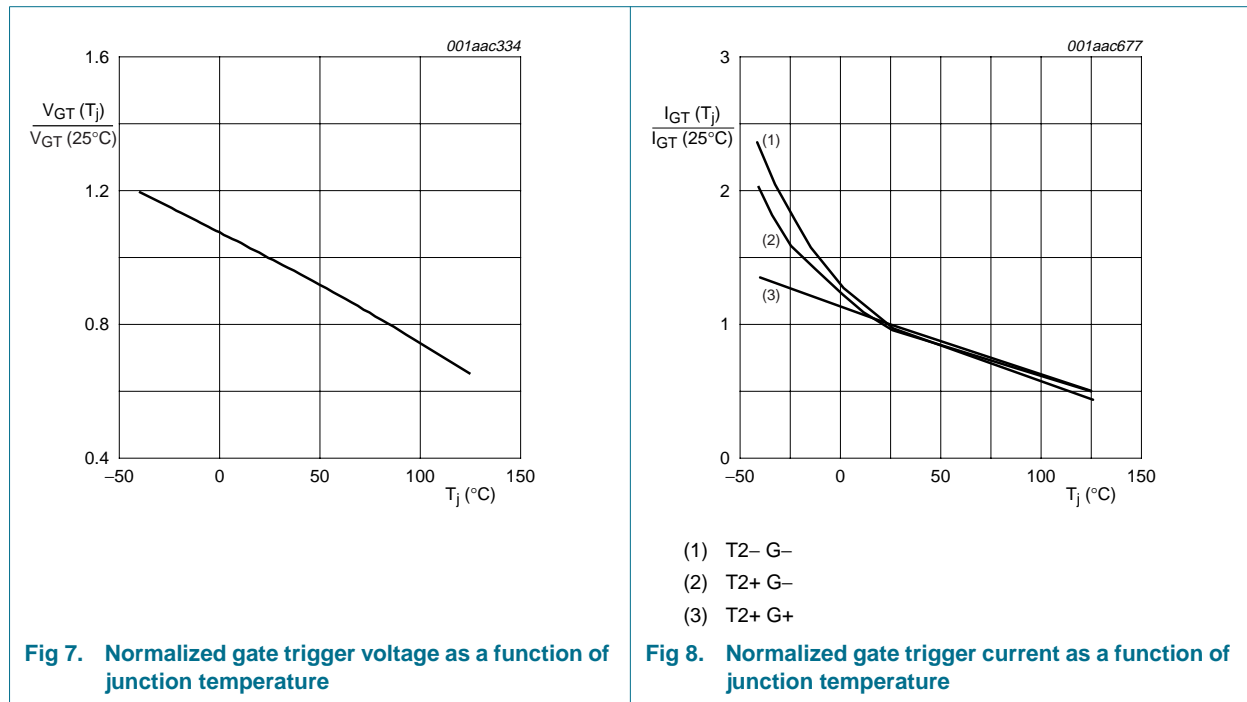
Fig 6. Transient thermal impedance from junction to mounting base as a function of pulse width

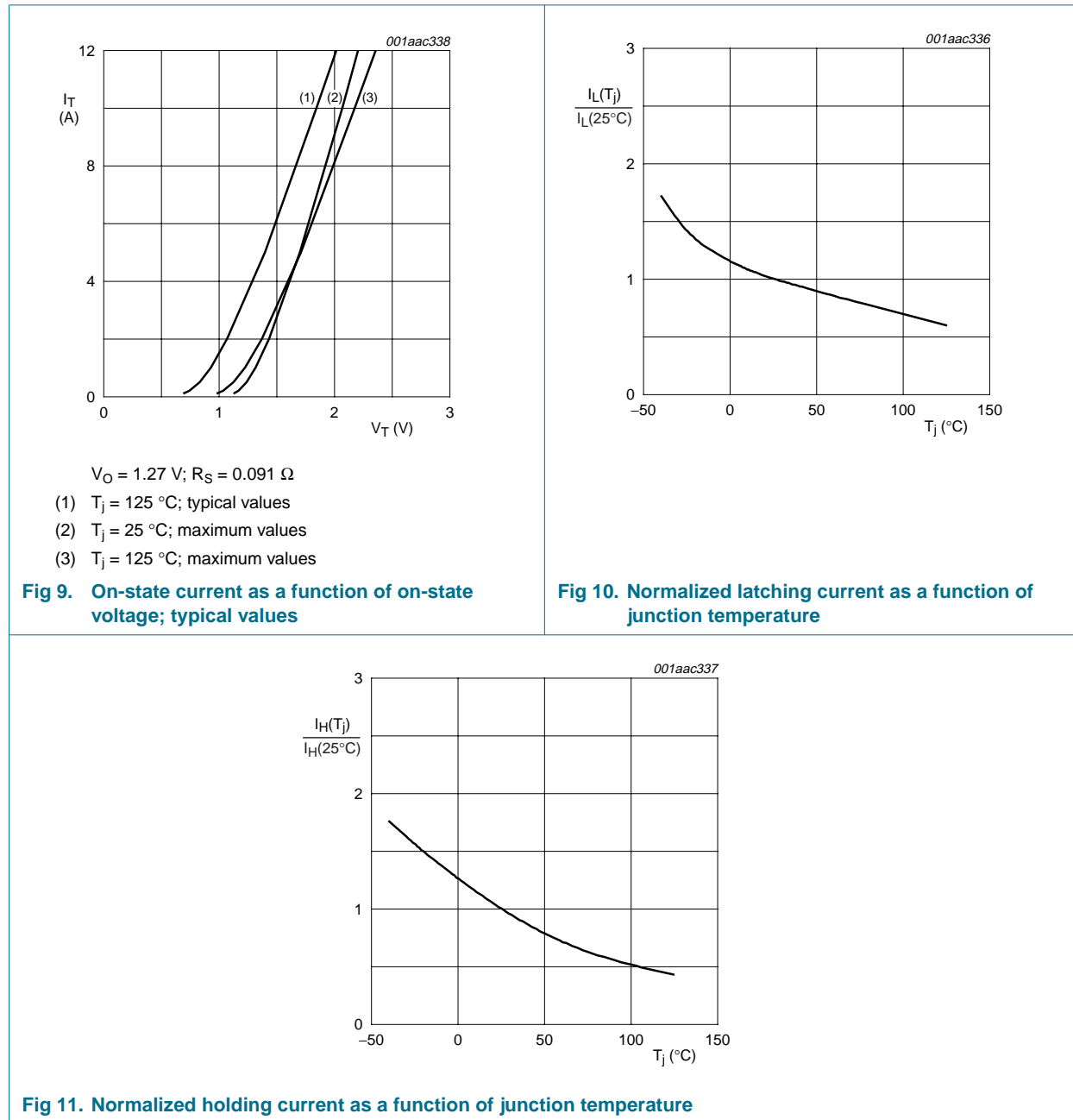
6. Static characteristics

Table 5: Static characteristics
T_j = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	BTA204S-600B BTA204S-800B			BTA204S-600C BTA204S-800C			Unit
			Min	Typ	Max	Min	Typ	Max	
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A see Figure 8 [1]							
		T2+ G+	-		50	-	-	35	mA
		T2+ G-	-	-	50	-	-	35	mA
		T2- G-	-	-	50	-	-	35	mA
I _L	latching current	V _D = 12 V; I _{GT} = 0.1 A; see Figure 10							
		T2+ G+	-	-	30	-	-	20	mA
		T2+ G-	-	-	45	-	-	30	mA
		T2- G-	-	-	30	-	-	20	mA
I _H	holding current	V _D = 12 V; I _{GT} = 0.1 A; see Figure 11	-	-	30	-	-	20	mA
V _T	on-state voltage	I _T = 5 A; see Figure 9	-	1.4	1.7	-	1.4	1.7	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; see Figure 7	-	0.7	1.5	-	0.7	1.5	V
		V _D = 400 V; I _T = 0.1 A; T _j = 125 °C	0.25	0.4	-	0.25	0.4	-	V
I _D	off-state leakage current	V _D = V _{DRM(max)} ; T _j = 125 °C	-	0.1	0.5	-	0.1	0.5	mA

[1] Device does not trigger in the T2- G+ quadrant.





7. Dynamic characteristics

Table 6: Dynamic characteristics

$T_j = 25\text{ °C}$ unless otherwise specified.

Symbol	Parameter	Conditions	BTA204S-600B BTA204S-800B			BTA204S-600C BTA204S-800C			Unit
			Min	Typ	Max	Min	Typ	Max	
dV_D/dt	critical rate of rise of off-state voltage	$V_{DM} = 0.67V_{DRM(max)}$; $T_j = 125\text{ °C}$; exponential waveform; gate open circuit	1000	-	-	1000	-	-	V/ μ s
dI_{com}/dt	critical rate of change of commutating current	$V_{DM} = 400\text{ V}$; $T_j = 125\text{ °C}$; $I_{T(RMS)} = 4\text{ A}$; $dV_{com}/dt = 20\text{ V}/\mu\text{s}$; gate open circuit	6	-	-	3	-	-	A/ms
t_{gt}	gate controlled turn-on time	$I_{TM} = 12\text{ A}$; $V_D = V_{DRM(max)}$; $I_G = 0.1\text{ A}$; $dI_G/dt = 5\text{ A}/\mu\text{s}$	-	2	-	-	2	-	μ s

8. Package information

Refer to mounting instructions for SOT428 (DPAK) package.

Plastic meets requirements of UL94 V-0 at $1/8$ inch.

9. Package outline

Plastic single-ended surface mounted package (DPAK); 3 leads (one lead cropped)

SOT428

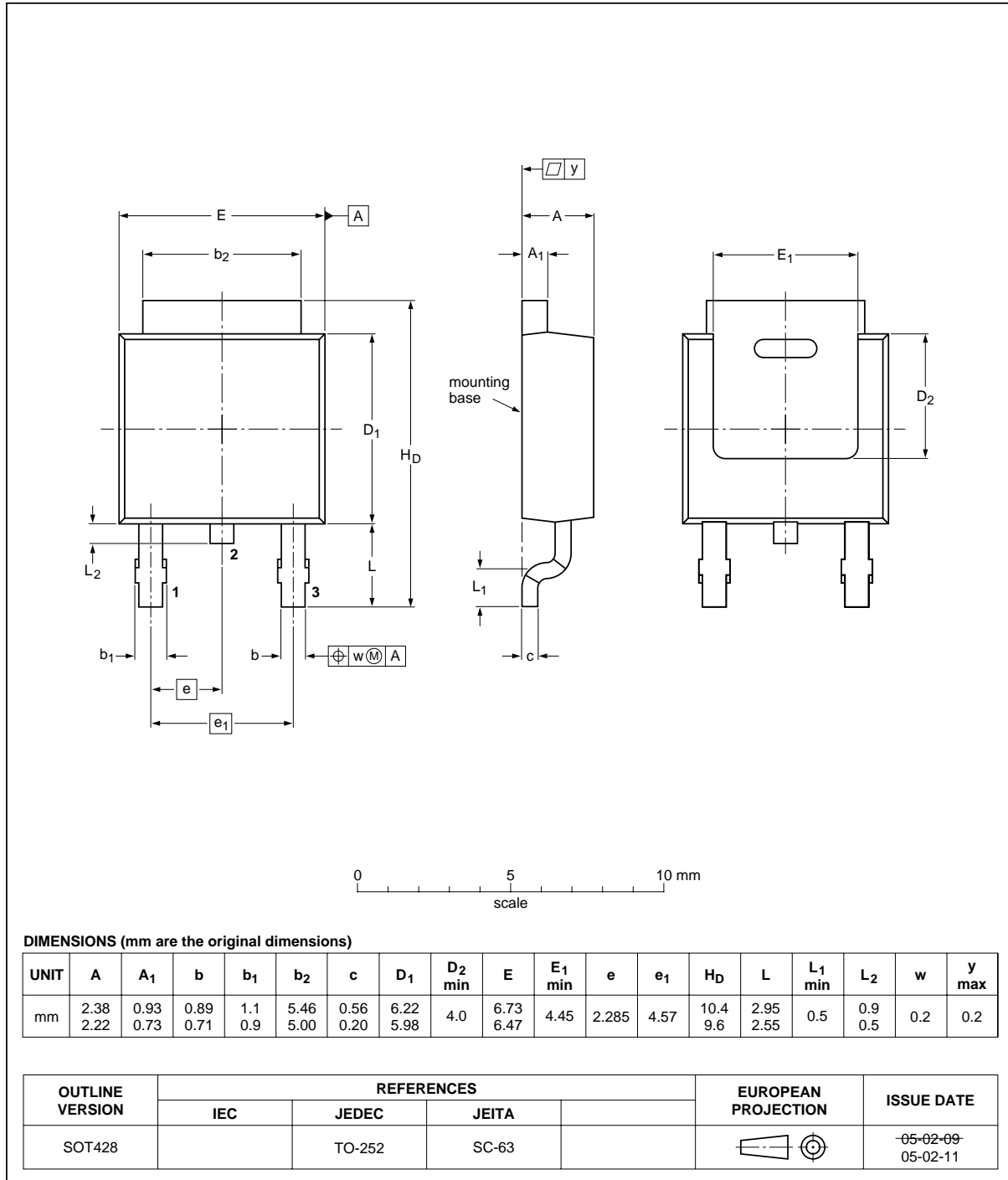
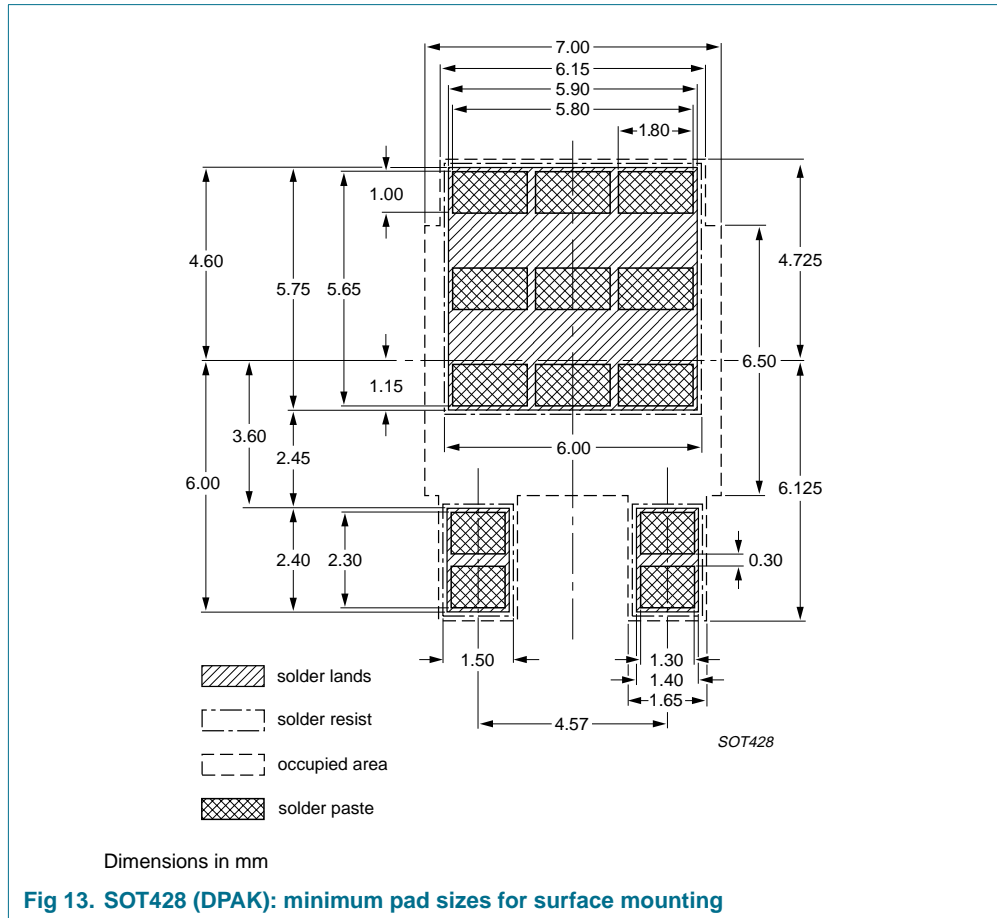


Fig 12. Package outline SOT428 (DPAK)

10. Mounting



11. Revision history

Table 7: Revision history

Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
BTA204S_SER_B_C_3	20050524	Product data sheet	-	9397 750 14862	BTA204S_SERIES_B_C_2
Modifications:			<ul style="list-style-type: none">• The format of this data sheet has been redesigned to comply with the new presentation and information standard of Philips Semiconductors• 500 V types removed• Alternative pinning types removed		
BTA204S_SERIES_B_C_2	19981201	Product specification	-	n.a.	BTA204S_SERIES_B_C_1
BTA204S_SERIES_B_C_1	19971001	Objective specification	-	n.a.	-

12. Data sheet status

Level	Data sheet status [1]	Product status [2] [3]	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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